

PDTA144TE,115 Datasheet



DiGi Electronics Part Number PDTA144TE,115-DG Manufacturer NXP USA Inc. Manufacturer Product Number PDTA144TE,115 Description **Detailed Description** d 50 V 100 mA 150 mW Surface Mount SC-75

TRANS PREBIAS PNP 50V 0.1A SC75 Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biase

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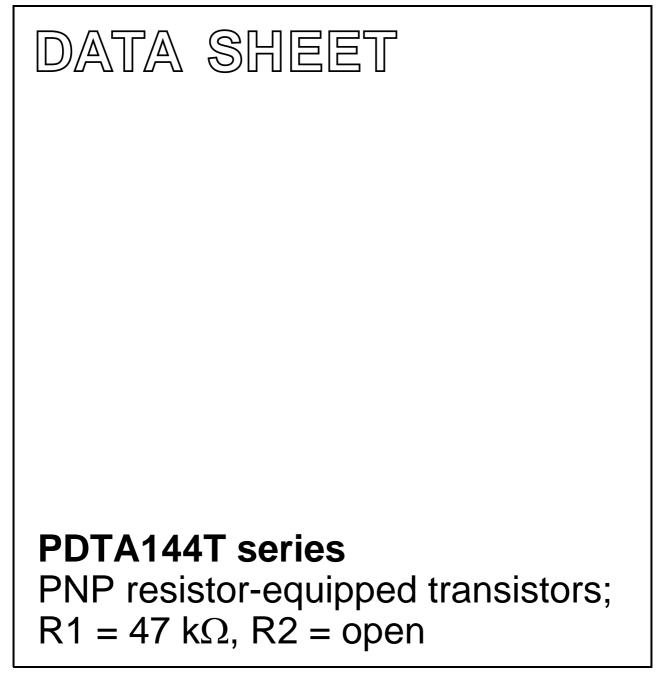
Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PDTA144TE,115	NXP USA Inc.
Manufacturer:	Series:
NXP USA Inc.	
Packaging:	Part Status:
Tape & Reel (TR)	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP - Pre-Biased	100 mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50 V	47 kOhms
DC Current Gain (hFE) (Min) @ lc, Vce:	Vce Saturation (Max) @ lb, lc:
100 @ 1mA, 5V	150mV @ 500μA, 10mA
Current - Collector Cutoff (Max):	Power - Max:
1μΑ	150 mW
Mounting Type:	Package / Case:
Surface Mount	SC-75, SOT-416
Supplier Device Package:	Base Product Number:
SC-75	PDTA144

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 Apr 27 2004 Aug 05



PDTA144T series

Product data sheet

FEATURES

- · Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- · General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

PRODUCT OVERVIEW

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-	-50	V
lo	output current (DC)	-	-100	mA
R1	bias resistor	47	-	kΩ
R2	open	_	_	-

DESCRIPTION

PNP resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

	PACKAGE		MARKING CODE	NPN COMPLEMENT	
TYPE NUMBER	PHILIPS	EIAJ	MARKING CODE	NPN COMPLEMENT	
PDTA144TE	SOT416	SC-75	5B	PDTC144TE	
PDTA144TEF	SOT490	SC-89	2M	PDTC144TEF	
PDTA144TK	SOT346	SC-59	58	PDTC144TK	
PDTA144TM	SOT883	SC-101	F9	PDTC144TM	
PDTA144TS	SOT54 (TO-92)	SC-43	TA144T	PDTC144TS	
PDTA144TT	SOT23	_	*AF ⁽¹⁾	PDTC144TT	
PDTA144TU	SOT323	SC-70	*7A ⁽¹⁾	PDTC144TU	

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PNP resistor-equipped transistors; $R1 = 47 \text{ k}\Omega$, R2 = open

PDTA144T series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

			PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTA144TS		1 2 3	base collector emitter
PDTA144TE PDTA144TEF PDTA144TK PDTA144TT PDTA144TU	3 1 3 1 2 1 Top view MDB272	1 2 3	base emitter collector
PDTA144TM	2 1 Bottom view Bottom view MDB268	1 2 3	base emitter collector

PDTA144T series

ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
ITPE NOWIDER	NAME	DESCRIPTION	VERSION	
PDTA144TE	_	plastic surface mounted package; 3 leads	SOT416	
PDTA144TEF	_	plastic surface mounted package; 3 leads	SOT490	
PDTA144TK	_	plastic surface mounted package; 3 leads	SOT346	
PDTA144TM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm	SOT883	
PDTA144TS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54	
PDTA144TT	_	plastic surface mounted package; 3 leads	SOT23	
PDTA144TU	_	plastic surface mounted package; 3 leads	SOT323	

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	-50	V
V _{CEO}	collector-emitter voltage	open base	_	-50	V
V _{EBO}	emitter-base voltage	open collector	_	-5	V
lo	output current (DC)		_	-100	mA
I _{CM}	peak collector current		_	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT23	note 1	_	250	mW
	SOT54	note 1	_	500	mW
	SOT323	note 1	_	200	mW
	SOT346	note 1	-	250	mW
	SOT416	note 1	-	150	mW
	SOT490	notes 1 and 2	-	250	mW
	SOT883	notes 2 and 3	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

PDTA144T series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT23	note 1	500	K/W
	SOT54	note 1	250	K/W
	SOT323	note 1	625	K/W
	SOT346	note 1	500	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

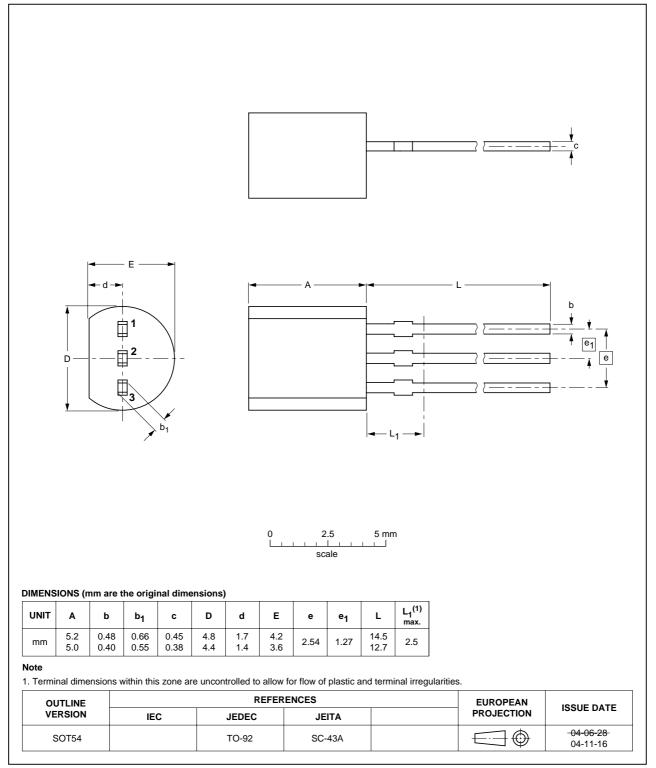
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; \text{ I}_{\text{E}} = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μA
		$V_{CE} = -30 \text{ V}; I_B = 0; T_j = 150 \text{ °C}$	-	-	-50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}$	-	-	-150	mV
R1	input resistor		33	47	61	kΩ
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = -10 V;$ f = 1 MHz	-	-	3	pF

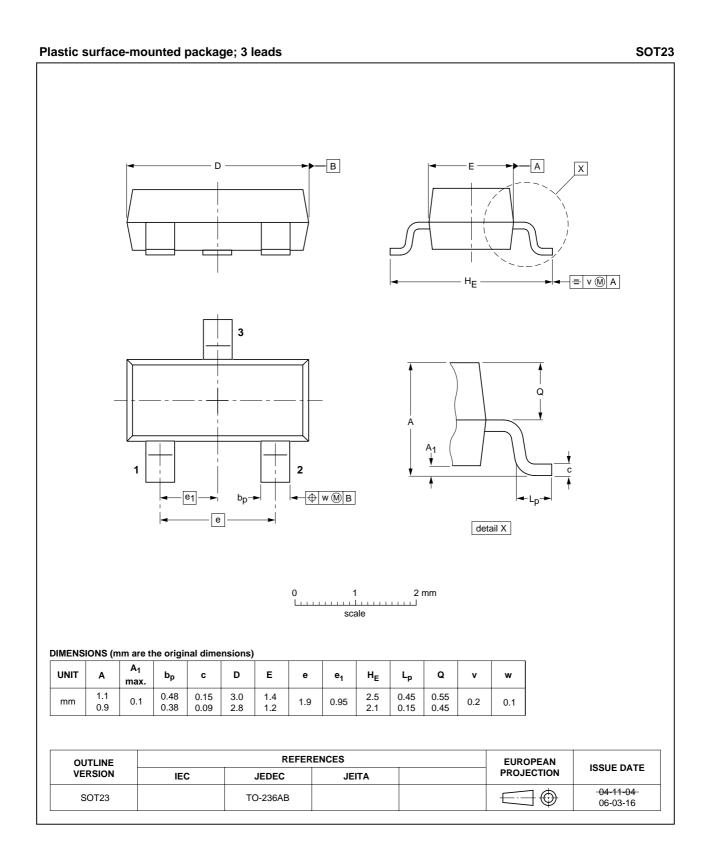
SOT54

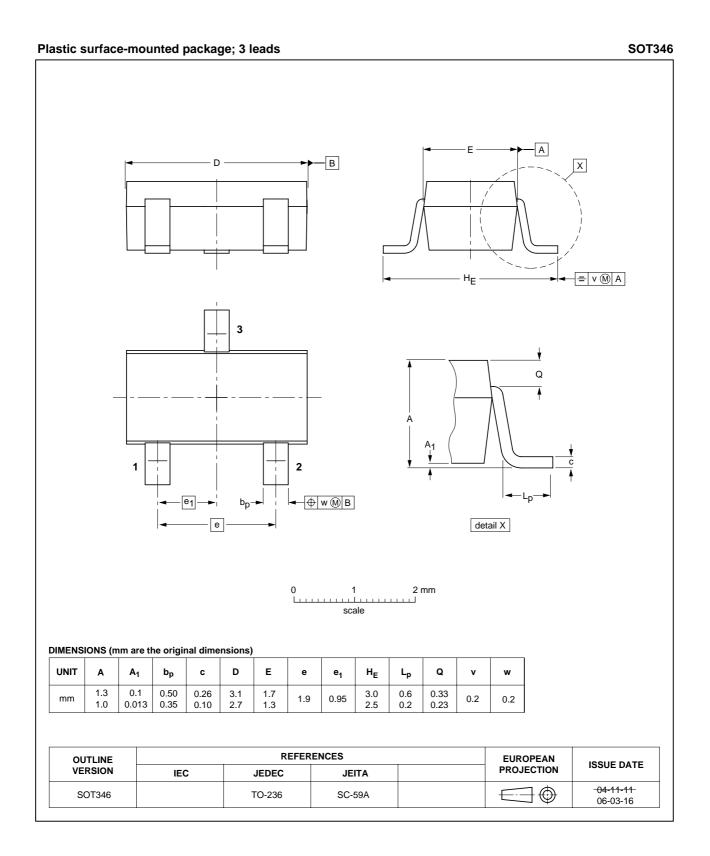
PNP resistor-equipped transistors; R1 = 47 k Ω , R2 = open

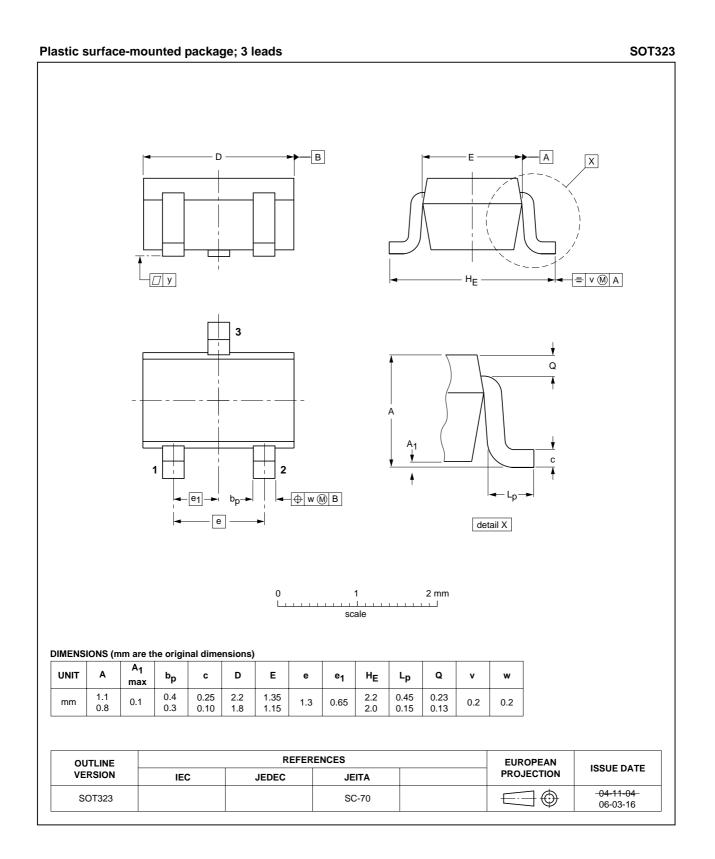
PACKAGE OUTLINES

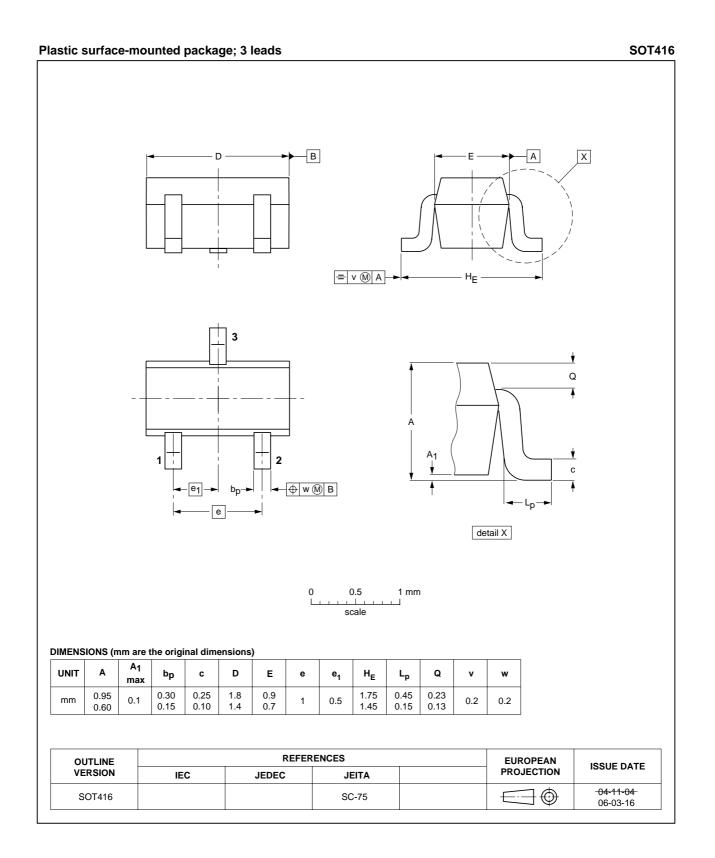
Plastic single-ended leaded (through hole) package; 3 leads

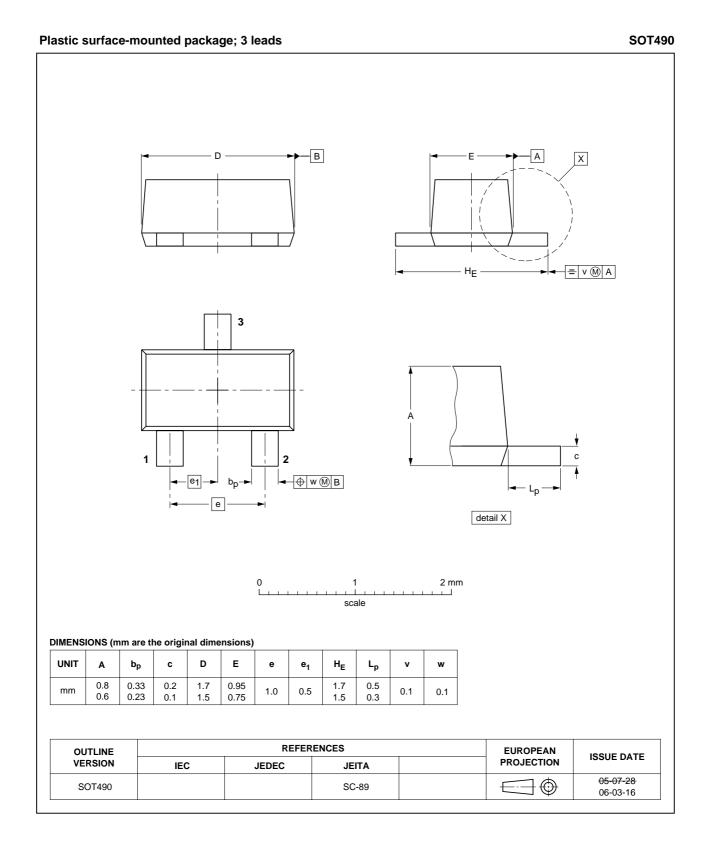


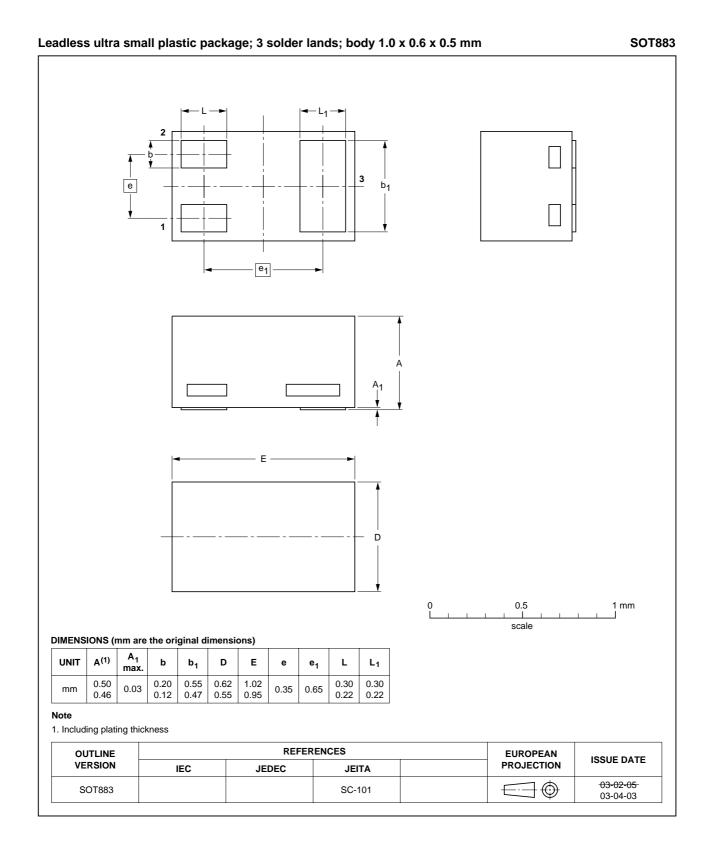












PDTA144T series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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Printed in The Netherlands

R75/03/pp14

Date of release: 2004 Aug 05

Document order number: 9397 750 13661





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